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*Title:* Shear-Rate Dependence in Dislocation Pile-ups at Asymmetric Tilt Boundaries in Aluminum

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## **Shear-Rate Dependence in Dislocation Pile-up Simulations at Asymmetric Tilt Boundaries in Aluminum**

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Materials deformation processes are increasingly approachable through atomistic methods. In one deformation process, dislocation pile-up at a grain boundary, how dislocations transmit through grain boundaries is of intense interest. Here dislocation pile-ups in an aluminum bicrystal with an asymmetric sigma-11 tilt grain boundary are simulated. Dislocations are initially distributed according to linear elastic estimates from a far-field stress of 40 MPa. The system is propagated for different periods of time, representing different shear rates. Incremental loading occurs every 40 ps or every 80 ps. In spite of the factor of two difference in shear rate, differences in the events are quite marked. At the higher rate, dislocations are transmitted on both available slip systems. The entities transmitted are perfect dislocations. At the slower rate, transmission and reflection events consist of multiple Shockley partial dislocations, parallel to each other, on one of the slip planes.

# Shear-Rate Dependence in Dislocation Pile-ups at Asymmetric Tilt Boundaries in Aluminum

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<sup>1</sup> MST-8: Structure/Property Relations

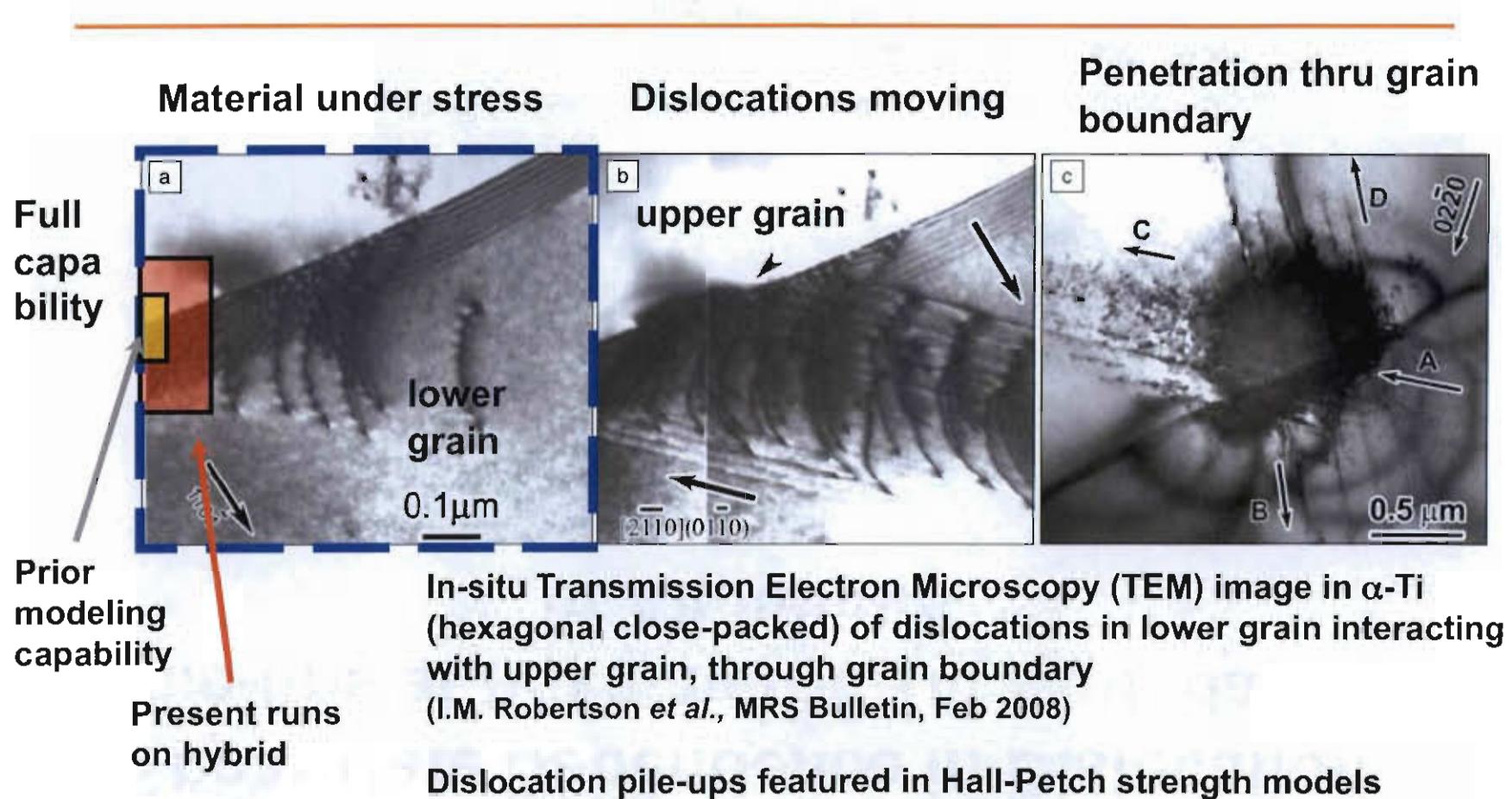
<sup>2</sup> T-1: Physics and Chemistry of Materials

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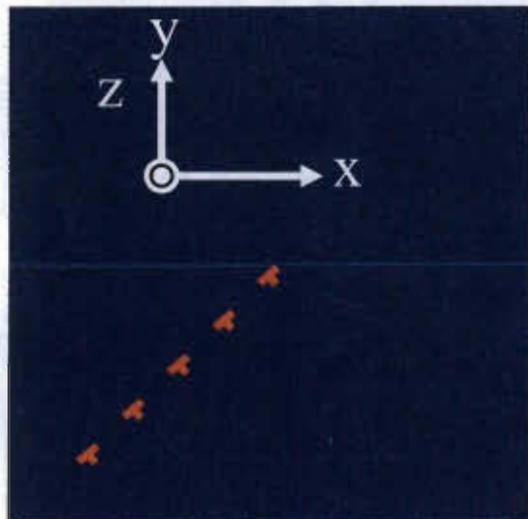
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Project on Spatio-Temporal Frontiers of Atomistic Simulations in the Petaflop  
Computational World

Collaborators: Art Voter, Danny Perez, Jim Hammerberg, Davis Tonks,  
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# Dislocation Pile-Up



# Grain Boundary Simulations



{111}top||{110}bottom  
 $\Sigma_{11}$  tilt

Ercolessi-Adams Embedded  
Atom Method Al

## Simulation cell

GBs : asymmetrical  $\Sigma_{11}$  in Al (x-z plane)

Boundary: periodic along z

Dimension: X = Y = 160 nm

z (nm): 3      10      20      30

atoms: 4      12.5      25      37

( $\times 10^6$ )

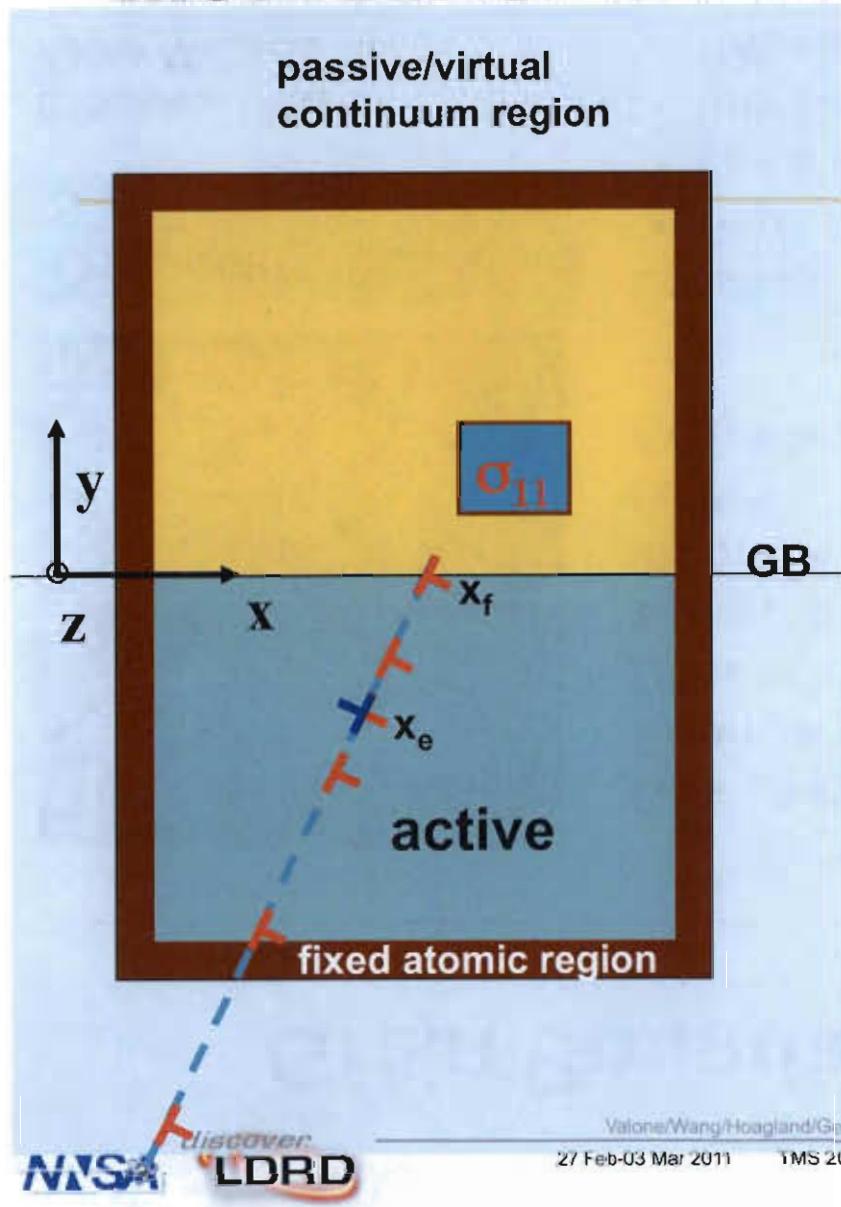
Active and passive dislocations

## MD simulations

Loading: uniaxial tension along the x axis

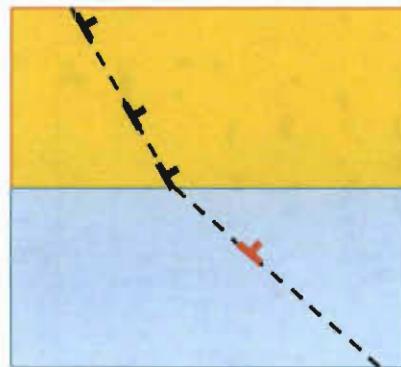
- Start at RSS = 0.75 GPa at 1<sup>st</sup> dislocation
- For a given stress, run MD for 50 ps
- Increase applied stress in 0.03 GPa
- Repeat MD

# Method for Introducing dislocations

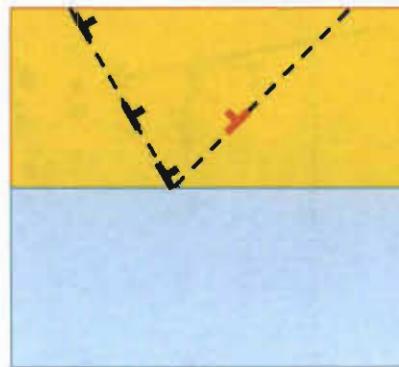


- 3 steps: Estimate-Introduce-Correct  
In order to minimize shock effects:
  - Estimate
    - Predict the position  $x_e$  for the next dislocation using elastic solution.
  - Introduce
    - A dislocation  $b$  at  $x_e$ .
    - Relax at room temperature for 40 ps followed by quenching.
    - Determine the final position ( $x_f$ ).
  - Correct
    - Introducing a dislocation  $b$  at  $x_f$  and the other  $-b$  at  $x_e$  by applying their displacements in the fixed region.
    - Relax for 10 ps. The displacements in the boundary region is corrected.

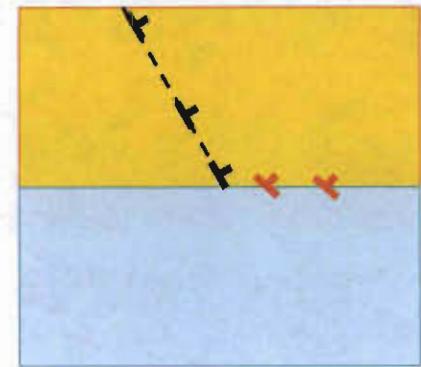
# Grain Bdy-Dislocations Interactions



transmission



reflection



climb and/or glide

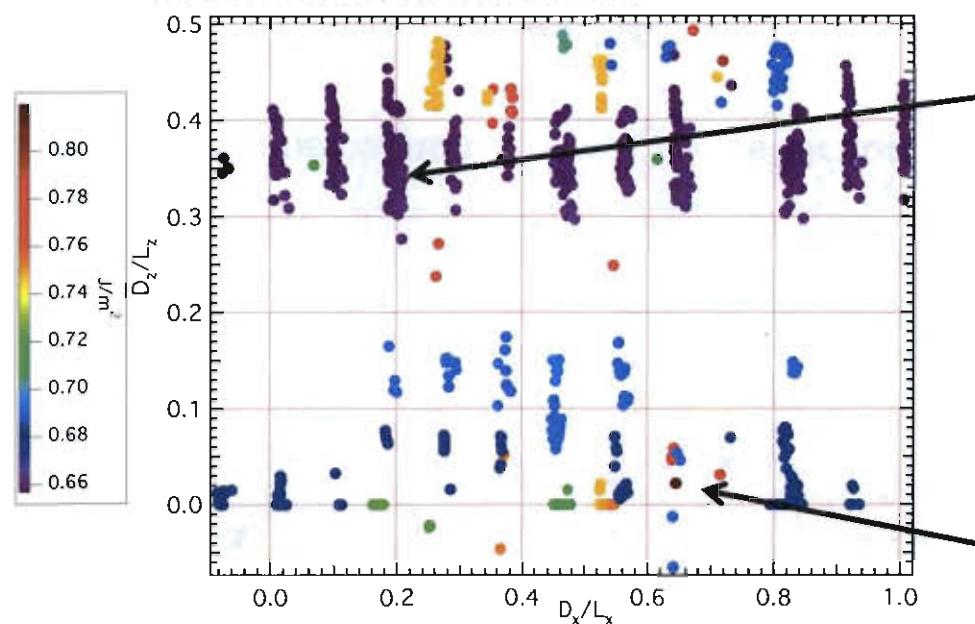
Common deformation modes:  
Instability in GB structures  
Deformation twinning, shear  
band formation  
Intergranular fracture  
Individually or coupled

## Issues

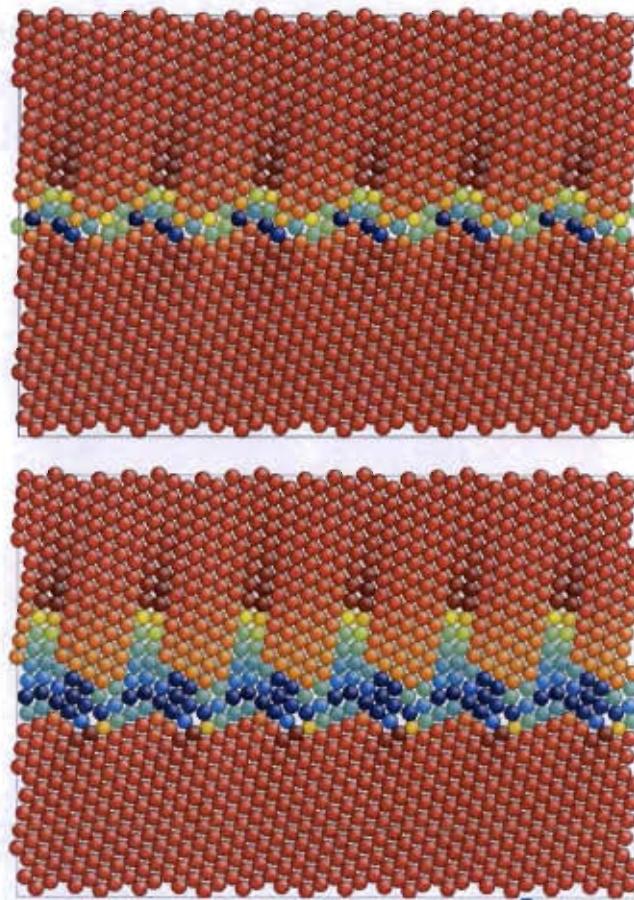
1. Kinetics of each unit event (no strain rate)
2. Influence of strain rate on each unit event
3. Multiple deformation modes

# Asymmetric $\Sigma_{11}$ Grain Boundary Energetics and Structures

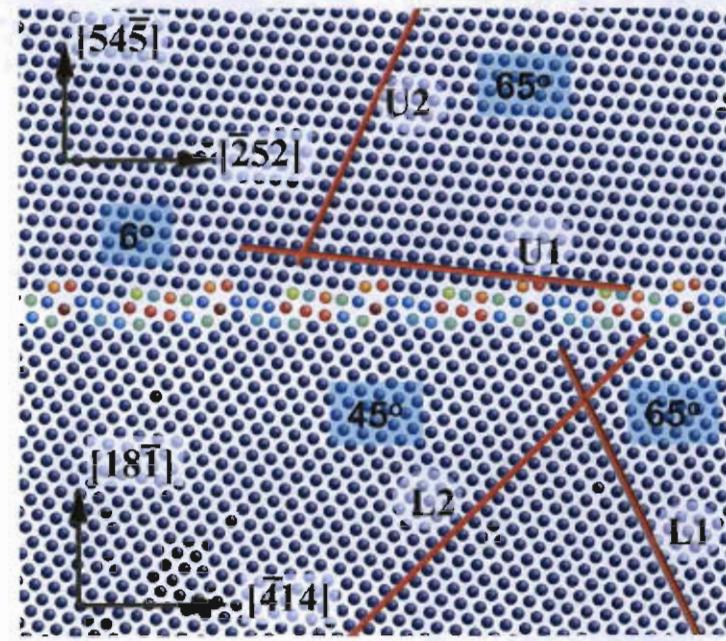
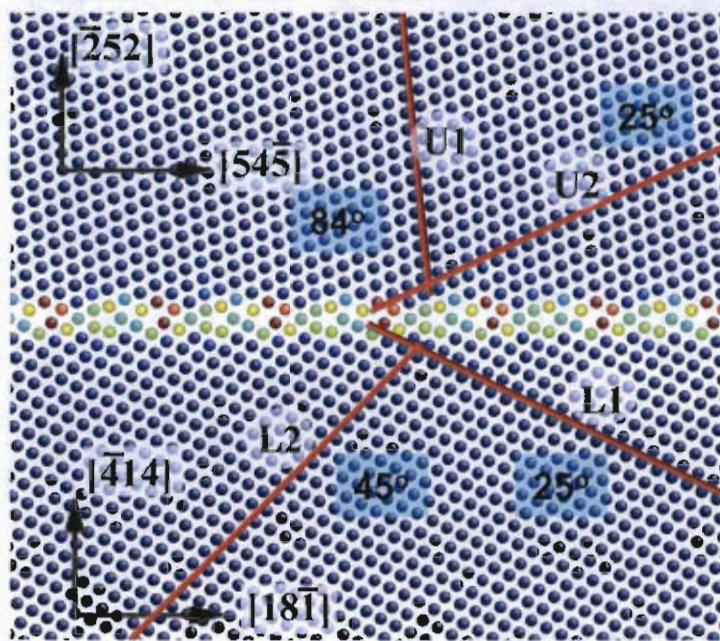
Local Minima Map



Fensin for Mishin Cu



# Asymmetric $\Sigma_{11}$ Grain Boundaries with Slip Planes



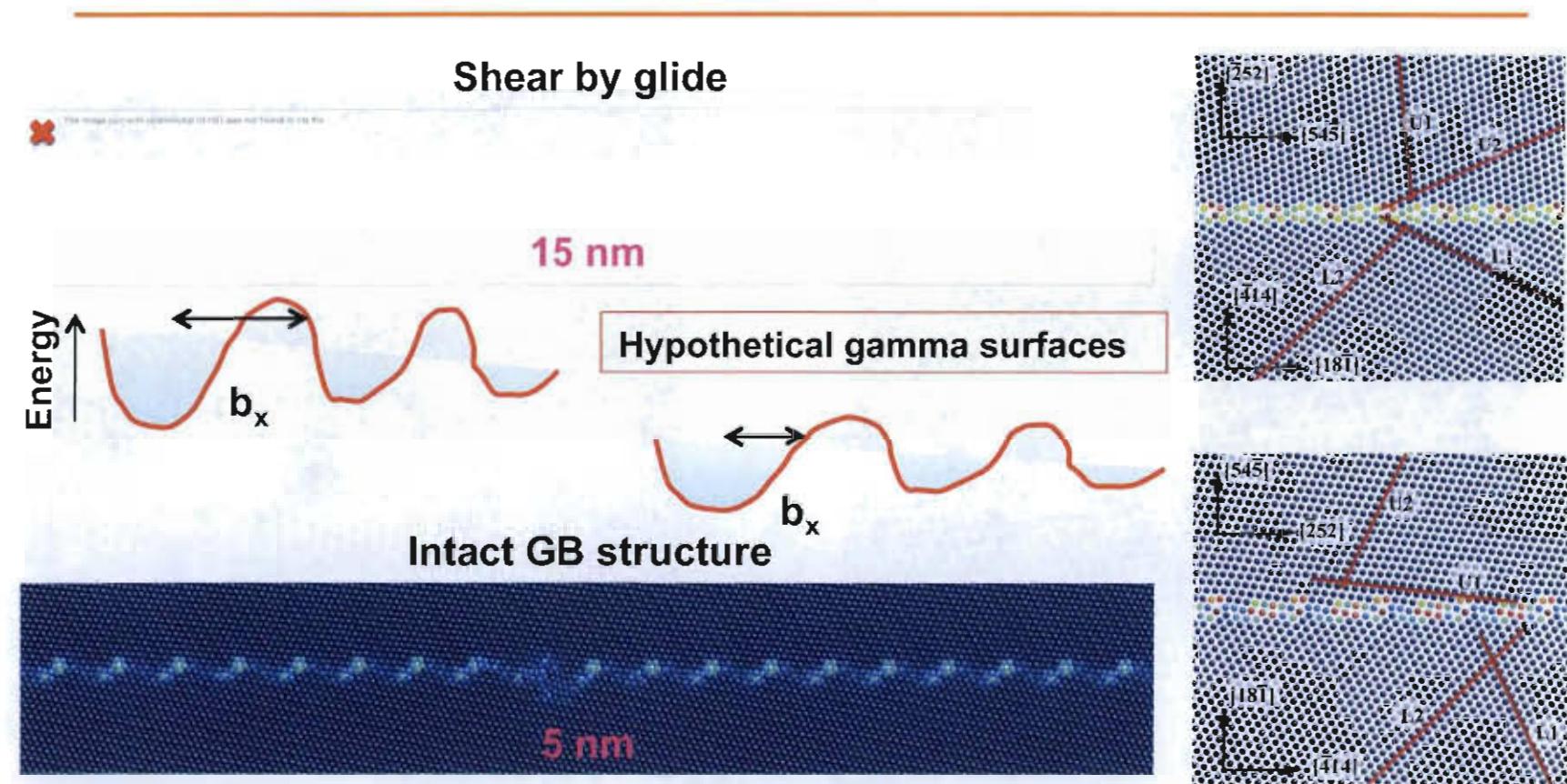
GB-1

GB-2

Three slip systems are evident in this study

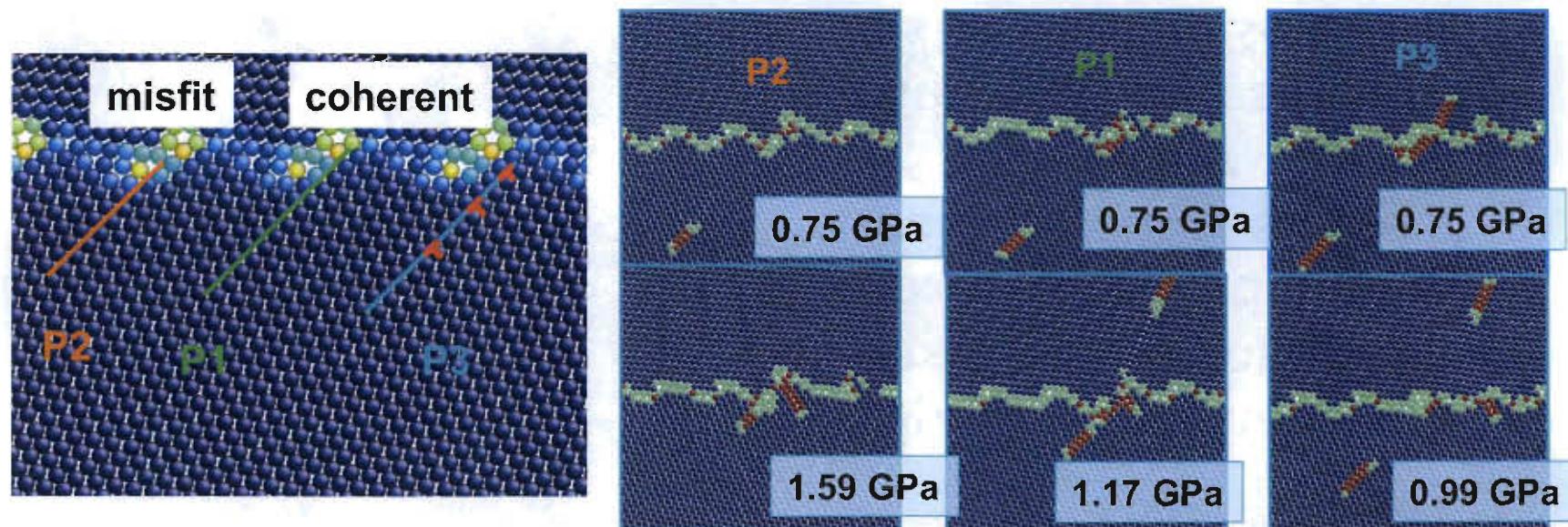
1. Dislocations pile up on L2 in GB-1 (transmission and reflection )
2. Dislocations pile up on L1 in GB-2 (reflection and climb)
3. Dislocations pile up on L2 in GB-2 (transmission)

# Single Dislocation Interacting with Grain Boundaries



# Slip-Plane/GB Intersection Alters Local Atomic Structures

Same dislocation pile-up on three adjacent slip planes



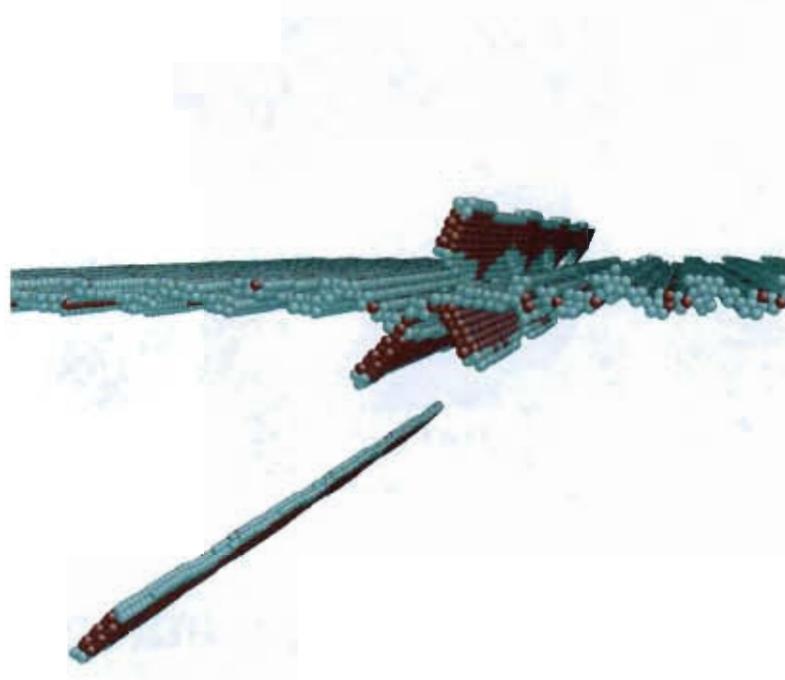
Transmission easier thru coherent zone  
Change of mechanism unknown

Detach

Detach

# Transmission and Reflection

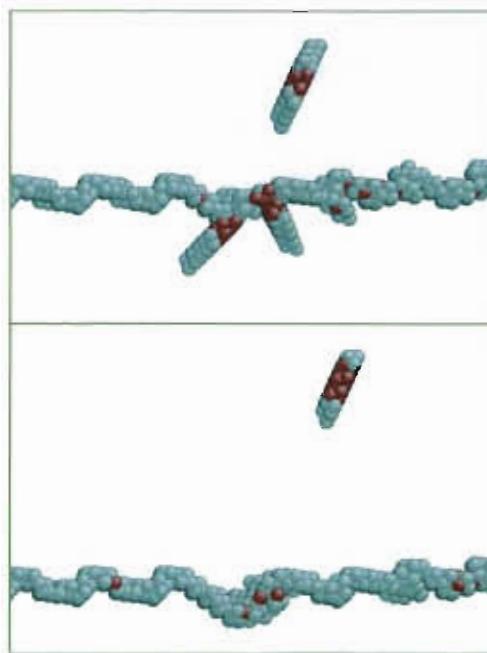
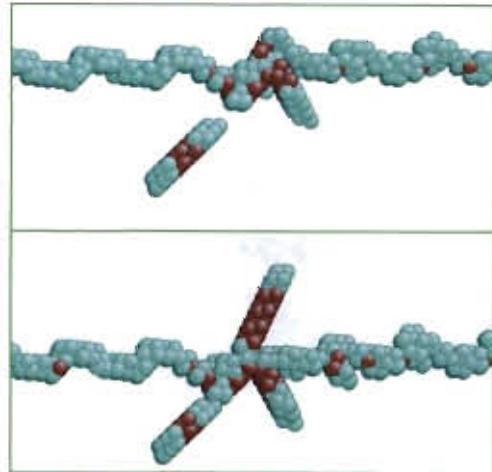
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1. Slip-plane normals and directions in both grains
2. Maximize directions and resolved shear stress in 2<sup>nd</sup> grain better
3. With minimal residual dislocation in GB better
4. Direct transmission rare
5. No shear-rate dependence

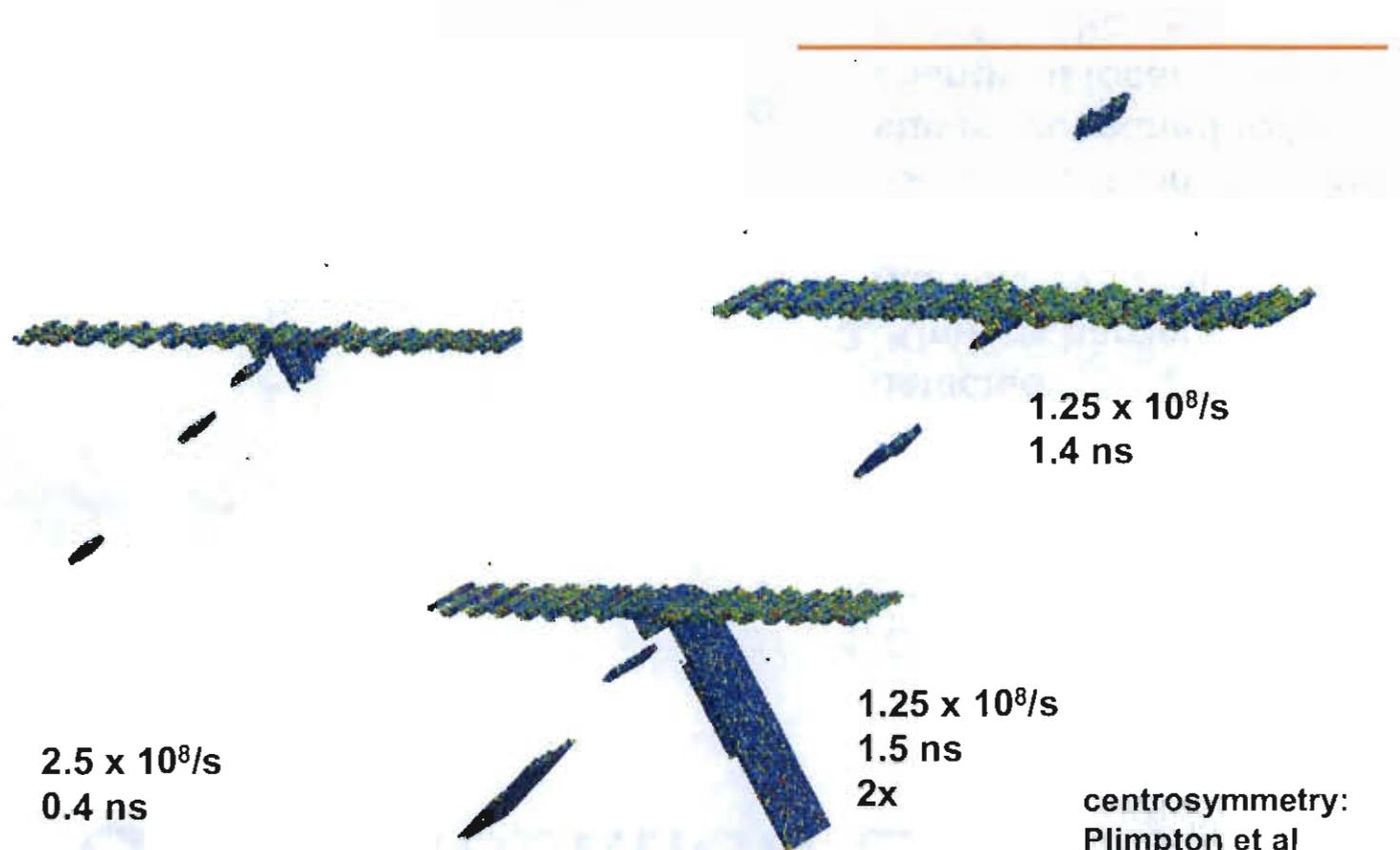
Lee et al. 1990

# GB-Dislocation Events



1. Dislocation detaches from GB at 1.17 GPa and 720 ps
2. Multiple local stable configurations are detected
3. Kinetics barriers are less than 0.5 eV for all transitions.
4. Before detachment, most states are related to the change of local structures near GB-slip plane intersection

# Transmission Events at Different Rates



# Summary

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- Grain orientations differ in preference for transmission or reflection
- Low-energy does not directly control grain boundary shear from interaction with dislocations
- Three dimensional dynamics crucial for estimating critical stresses for transmission even at high strain rate and nucleation of transmission events
- Slip-plane/GB intersection point added to list of controls
- Future issues
  - Multiple deformation modes
  - Much lower strain rates, coupling to AMD
  - Refine choices of orientations, loading conditions in search of mechanisms***